Product data sheet

## 1. Product profile

## 1.1 General description

Four planar PIN diode array in SOT363 small SMD plastic package.

#### 1.2 Features and benefits

- High voltage current controlled RF resistor for RF attenuators
- Low diode capacitance
- Very low series inductance
- Low distortion

## 1.3 Applications

- RF attenuators
- (SAT) TV applications
- Car radio applications

## 2. Pinning information

Table 1. Discrete pinning

Pin	Description	Simplified outline	Graphic symbol
1	anode diode 1	D. D. D.	
2	cathode diode 2	6 5 4	6 5 4
3	anode diode 3 / cathode diode 4		
4	anode diode 4	0	
5	cathode diode 3	□1 □2 □3	1 2 3 sym118
6	anode diode 2 / cathode diode 1		

## 3. Ordering information

Table 2. Ordering information

Type number	Package				
	Name	Description	Version		
BAP70AM	-	plastic surface-mounted package; 6 leads	SOT363		



Silicon PIN diode array

# 4. Marking

Table 3. Marking

Type number	Marking code	Description
BAP70AM	N9*	* = - : made in Hong Kong
		* = p : made in Hong Kong
		* = t : made in Malaysia

# 5. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_R$	reverse voltage		-	50	V
I <sub>F</sub>	forward current		-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>sp</sub> = 90 °C	-	300	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

## 6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		260	K/W

**Product data sheet** 

## 7. Characteristics

Table 6. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 50 mA	-	0.9	1.1	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 50 V	-	-	< 100	nA
$C_d$	diode capacitance	see Figure 1; f = 1 MHz;				
		V <sub>R</sub> = 0 V	-	570	-	fF
		V <sub>R</sub> = 1 V	-	400	-	fF
		V <sub>R</sub> = 5 V	-	270	-	fF
		V <sub>R</sub> = 20 V	-	200	250	fF
$r_D$	diode forward resistance	see Figure 2; f = 100 MHz;				
		I <sub>F</sub> = 0.5 mA	-	77	100	Ω
		I <sub>F</sub> = 1 mA	-	40	50	Ω
		I <sub>F</sub> = 10 mA	-	5.4	7	Ω
		I <sub>F</sub> = 100 mA	-	1.4	1.9	Ω
τ∟	charge carrier life time	when switched from I <sub>F</sub> = 10 mA to I <sub>R</sub> = 6 mA; R <sub>L</sub> = 100 $\Omega$ ; measured at I <sub>R</sub> = 3 mA		1.25	-	μS
L <sub>S</sub>	series inductance	I <sub>F</sub> = 100 mA; f = 100 MHz	-	0.6	-	nH

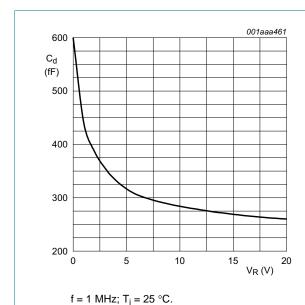
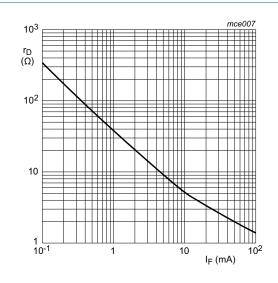


Fig 1. Diode capacitance as a function of reverse voltage; typical values



f = 100 MHz;  $T_j = 25 \text{ °C}$ .

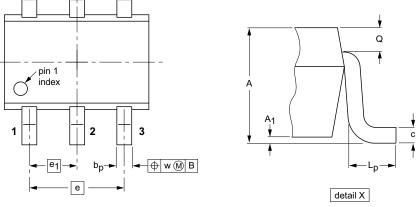
Fig 2. Diode forward resistance as a function of forward current; typical values

**SOT363** 

# 8. Package outline

Plastic surface-mounted package; 6 leads

# 



0	1	2 mm			
scale					

#### **DIMENSIONS** (mm are the original dimensions)

UNIT	Α	A <sub>1</sub> max	bp	С	D	E	е	e <sub>1</sub>	HE	Lp	Ø	v	w	у
mm	1.1 0.8	0.1	0.30 0.20	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.25 0.15	0.2	0.2	0.1

OUTLINE		REFER	RENCES		ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT363			SC-88			<del>04-11-08</del> 06-03-16

Fig 3. Package outline SOT363

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Silicon PIN diode array

## 9. Abbreviations

Table 7. Abbreviations

Acronym	Description			
PIN	-type, Intrinsic, N-type			
SMD	Surface Mounted Device			
RF	Radio Frequency			
SAT	SATellite			

# 10. Revision history

## Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP70AM v.4	20140307	Product data sheet	-	BAP70AM v.3
Modifications:	<ul> <li>Rollback to pre</li> </ul>	vious version		
BAP70AM v.3	20140127	Product data sheet	-	BAP70AM v.2
BAP70AM v.2	20100907	Product data sheet	-	BAP70AM v.1
BAP70AM v.1	20061120	Product data sheet	-	-

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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#### Silicon PIN diode array

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# **BAP70AM**

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